UNISONIC TECHNOLOGIES CO., LTD

MMBTA94

PNP SILICON TRANSISTOR

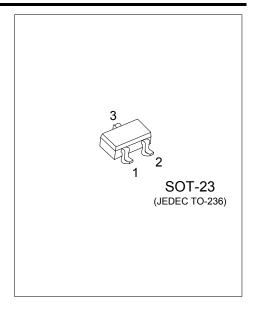
HIGH VOLTAGE TRANSISTOR

■ FEATURES

- * Collector-Emitter Voltage: V_{CEO} = -400V
- * Collector Dissipation: P_{C(MAX)} = 350mW
- * Low Collector-Emitter Saturation Voltage

■ APPLICATIONS

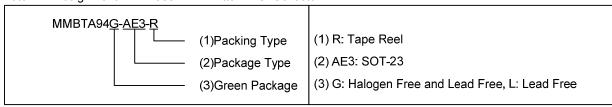
- * Telephone Switching
- * High Voltage Switch



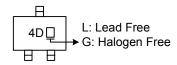
ORDERING INFORMATION

Ordering Number		Deelvere	Pin Assignment			Dealine	
Lead Free	Halogen Free	Package	1	2	3	Packing	
MMBTA94L-AE3-R	MMBTA94G-AE3-R	SOT-23	В	Е	С	Tape Reel	

Note: Pin Assignment: B: Base E: Emitter C: Collector



MARKING



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■ **ABSOLUTE MAXIMUM RATING** (T_A=25°C unless otherwise specified)

PARAMETER		SYMBOL	RATING	UNIT
Collector-Base Voltage		V _{CBO}	-400	V
Collector-Emitter Voltage		V _{CEO}	-400	V
Emitter-Base Voltage		V _{EBO}	-6	V
Collector Current	DC	Ic	-300	mA
Collector Current	Pulse	I _{CP}	-800	mA
Collector Current	Pulsed	I _{CM}	-800	mA
Collector Dissipation (Ta=25°C)		Pc	350	mW
Junction Temperature		TJ	+150	°C
Storage Temperature		T _{STG}	-40 ~ +150	°C

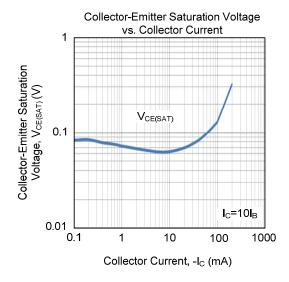
Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

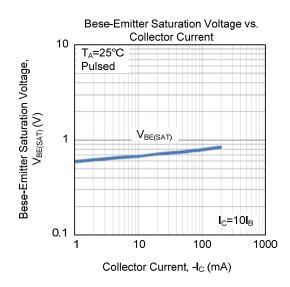
■ ELECTRICAL CHARACTERISTICS (T_A=25°C, unless otherwise specified)

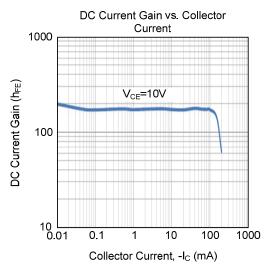
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Base Breakdown Voltage	BV _{CBO}	$I_C = -100 \mu A, I_E = 0$	-400			V
Collector-Emitter Breakdown Voltage	BV _{CEO}	$I_C = -1 \text{mA}, I_B = 0$	-400			V
Collector-Emitter Breakdown Voltage	BV _{CES}	$I_{C} = -100 \mu A, V_{BE} = 0$	-400			V
Emitter-Base Breakdown Voltage	BV _{EBO}	I _E = -100μA, I _C =0	-5			V
Collector Cut-off Current	I _{CBO}	V _{CB} = -300V, I _E =0			-100	nA
Collector Cut-off Current	I _{CES}	V _{CB} = -400V, V _{BE} =0			-1	μΑ
Emitter Cut-off Current	I _{EBO}	V_{EB} = -4V, I_C =0			100	nA
DC Current Gain (Note)	h _{FE}	V _{CE} = -10V, I _C = -1mA	60			
		V _{CE} = -10V, I _C = -10mA	70		300	
		V_{CE} = -10V, I_{C} = -50mA	70			
		V _{CE} = -10V, I _C = -100mA	40			
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	I_C = -10mA, I_B = -1mA			-0.20	V
		I_C = -50mA, I_B = -5mA			-0.5	V
Base-Emitter Saturation Voltage	$V_{BE(SAT)}$	I_C = -10mA, I_B = -1mA			-0.75	V
Output Capacitance	Cob	V_{CB} = -20 V , I_E =0, f =1 MHz			7	pF

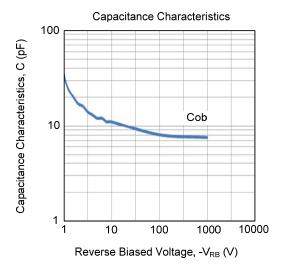
Note: Pulse test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.

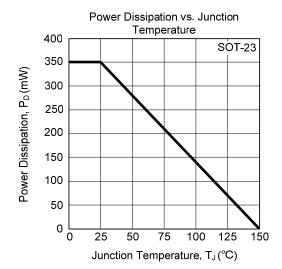
■ TYPICAL CHARACTERISTICS











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